



PERSISTENT MEMORY

P M SUMMIT

JANUARY 24, 2019 | SANTA CLARA, CA

Converging Memory and Storage

Frank Hady, PhD

Fellow, Intel Corporation

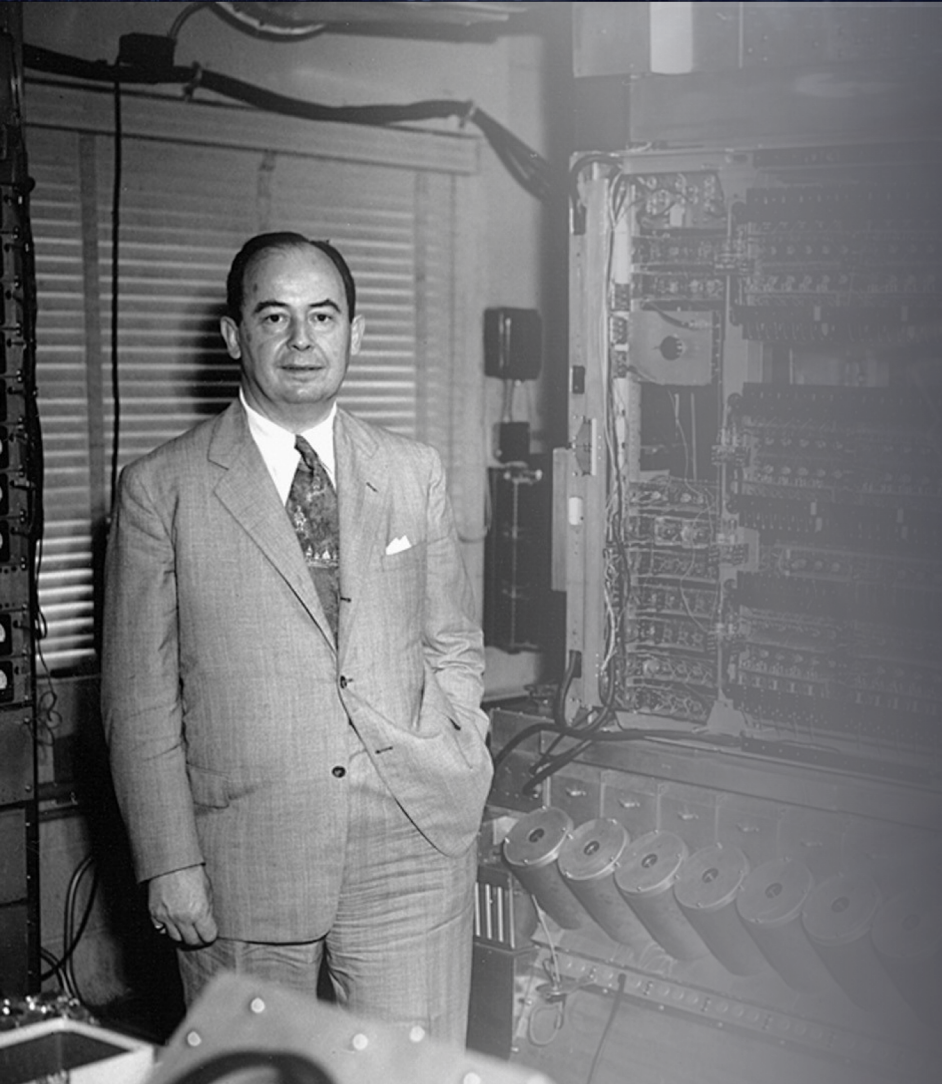
Chief Systems Architect, NVM Solutions Group

- ▶ PERFORMANCE RESULTS ARE BASED ON TESTING AS OF SPECIFIED DATES AND MAY NOT REFLECT ALL PUBLICLY AVAILABLE SECURITY UPDATES. SEE CONFIGURATION DISCLOSURE FOR DETAILS. NO PRODUCT CAN BE ABSOLUTELY SECURE
- ▶ THIS PRESENTATION INCLUDES FORWARD-LOOKING STATEMENTS RELATING TO INTEL. ALL STATEMENTS THAT ARE NOT HISTORICAL FACTS ARE SUBJECT TO A NUMBER OF RISKS AND UNCERTAINTIES, AND ACTUAL RESULTS MAY DIFFER MATERIALLY. PLEASE REFER TO INTEL'S MOST RECENT EARNINGS RELEASE, 10-Q AND 10-K FILINGS FOR THE RISK FACTORS THAT COULD CAUSE ACTUAL RESULTS TO DIFFER.

Notices and Disclosures

- ◆ [Performance results are based on testing as of [INSERT DATE] and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure.
- ◆ Software and workloads used in performance tests may have been optimized for performance only on Intel microprocessors. Performance tests, such as SYSmark and MobileMark, are measured using specific computer systems, components, software, operations and functions. Any change to any of those factors may cause the results to vary. You should consult other information and performance tests to assist you in fully evaluating your contemplated purchases, including the performance of that product when combined with other products. For more complete information about performance and benchmark results, visit <http://www.intel.com/benchmarks>
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“ Ideally one would desire an **indefinitely large memory capacity** such that any particular ... word would be **immediately available**. ... It **does not seem possible physically** to achieve such a capacity. We are therefore forced to recognize the possibility of **constructing a hierarchy of memories**, each of which has **greater capacity than the preceding** but which is **less quickly accessible**.”

**Preliminary Discussion of the Logical Design
of an Electronic Computing Instrument**

Arthur Burks, Herman Goldstine and John von Neumann, 1946

MEMORY AND STORAGE HIERARCHY

MEMORY

DRAM
HOT TIER

1 DIMM:
10s GB
<100ns

90/10 LOCALITY "RULE"
10X CAPACITY
1/10TH PERFORMANCE

STORAGE

1000X

3D NAND SSD
WARM TIER

1 SSD:
10s TB
<100μsecs

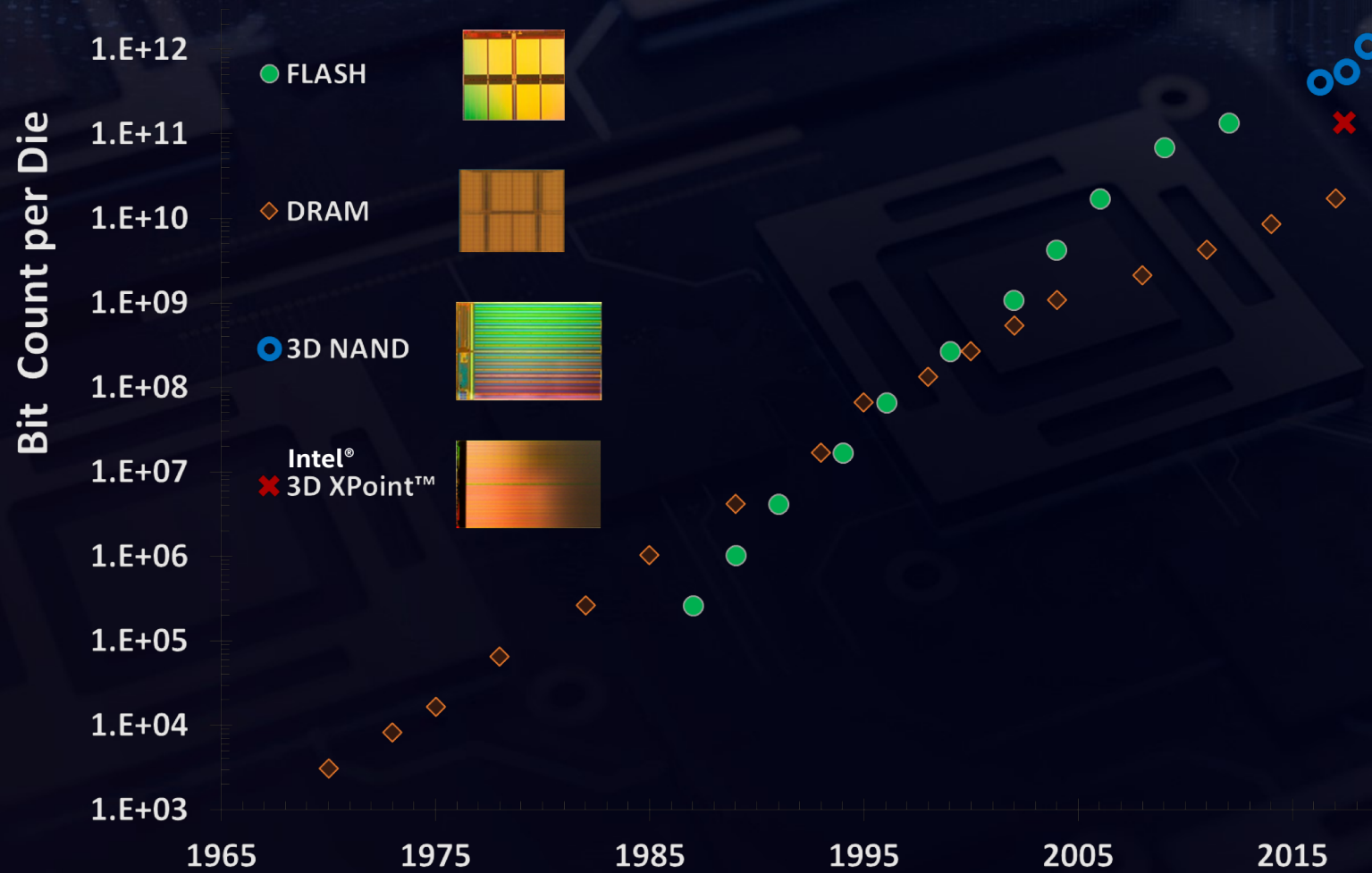
- 10x performance

100X

HDD / TAPE
COLD TIER

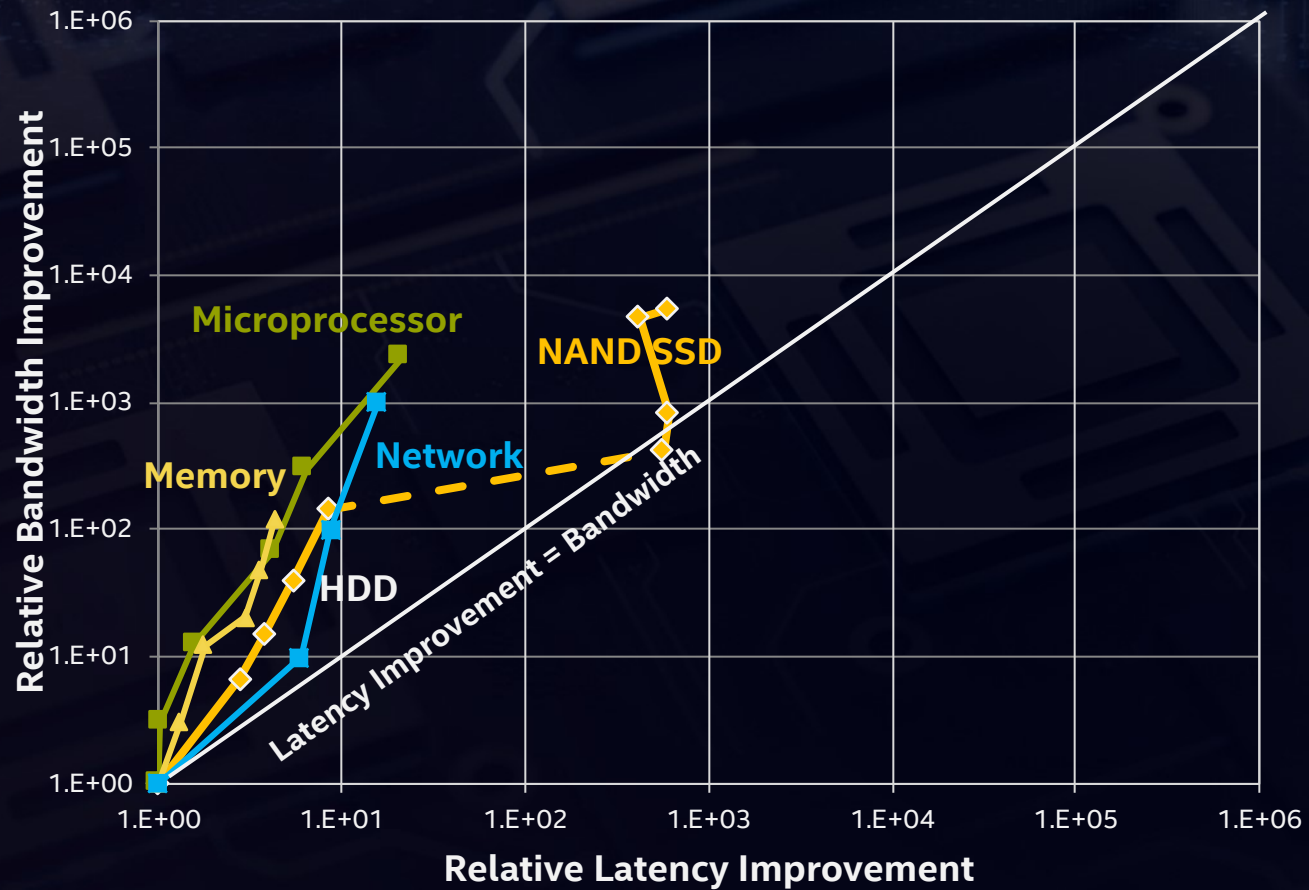
1 HDD:
10s TB
<10 msecs

CAPACITY : TECHNOLOGY SCALING



DRAM SCALING SLOWED, NAND SCALING KEPT PACE

PERFORMANCE: TECHNOLOGY SCALING



Source: "Latency lags Bandwidth"
– David Patterson Comms. of the
ACM, Oct 2004 Vol 47, No 10

NAND SSD data points added
by Intel Based on product brief
specifications for Intel NAND
SSDs available at www.intel.com

CONCLUSIONS: EVOLUTIONARY IMPROVEMENTS DELIVER IMPROVED BANDWIDTH
ONLY NEW TECHNOLOGIES CAN DELIVER IMPROVED LATENCY

MEMORY AND STORAGE HIERARCHY GAPS

MEMORY

DRAM
HOT TIER

10s GB
<100ns

CAPACITY GAP

STORAGE

STORAGE PERFORMANCE GAP

3D NAND SSD
WARM TIER

10s TB
<100μsecs

COST PERFORMANCE GAP

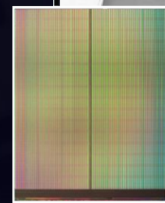
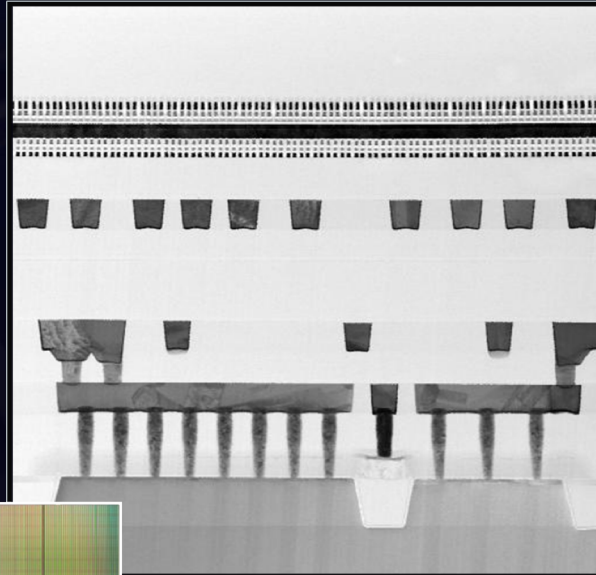
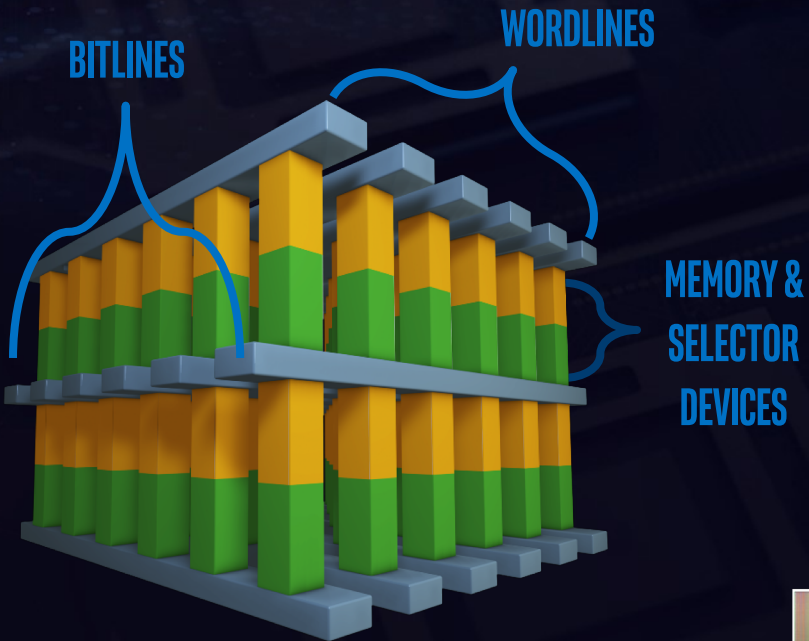
HDD / TAPE
COLD TIER

10s TB
<10 msecs

SOLUTION MUST MEET:

- **CAPACITY**
- **SYSTEM PERFORMANCE**
- **SYSTEM FIT**

A CONVERGENT MEMORY

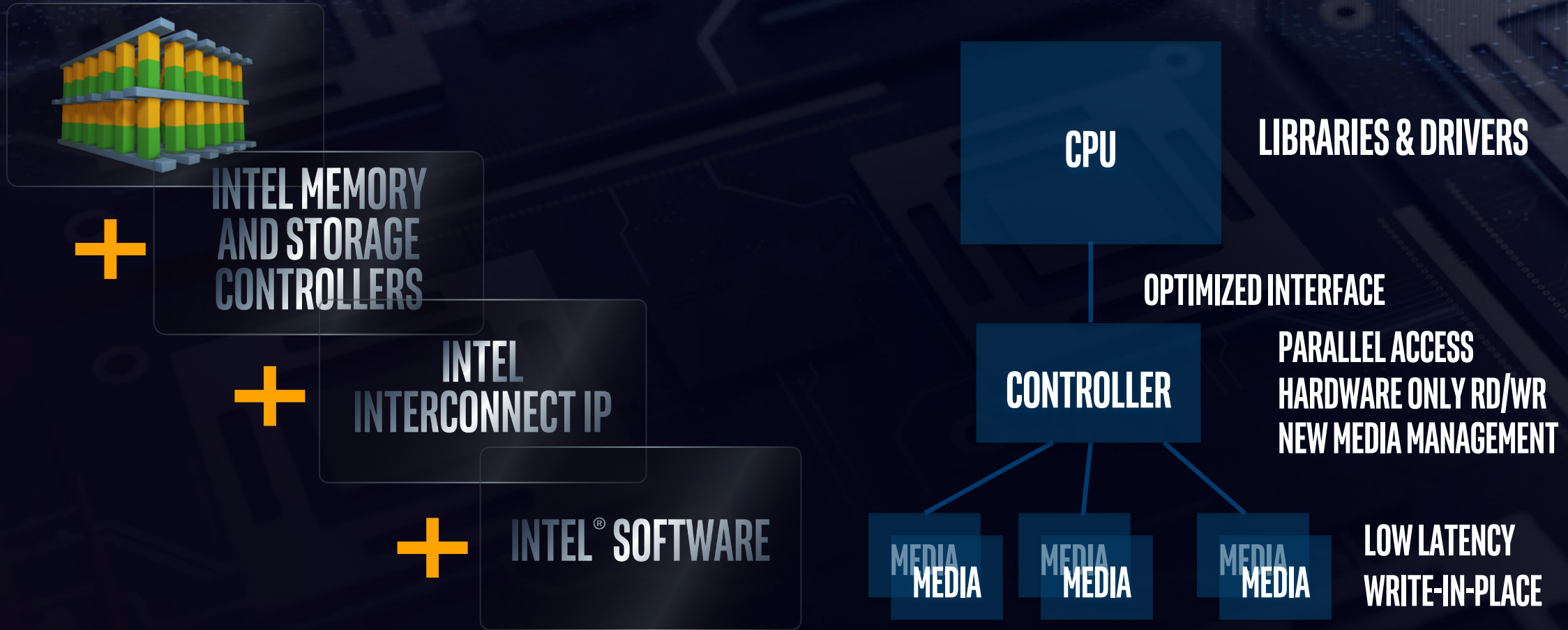


20NM 2 DECK 128GBIT INTEL®
3D XPOINT™ MEMORY

Desirable Attributes: Non-volatile, Low Cost, High Performance

- Memory in atomistic state, not electrostatic
→ **Non-Volatile** and Scalable
- Simple scalable structure + 3D technology
→ **Large Memory Capacity**
- Fast switching materials + local low resistance metal interconnect
→ **Immediately Available**
- Individual Cell Access
→ **Word Access**

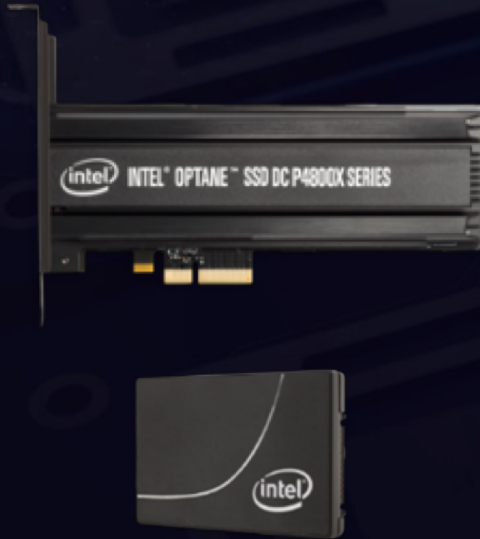
INTEL® OPTANE™ TECHNOLOGY: BUILDING BLOCKS



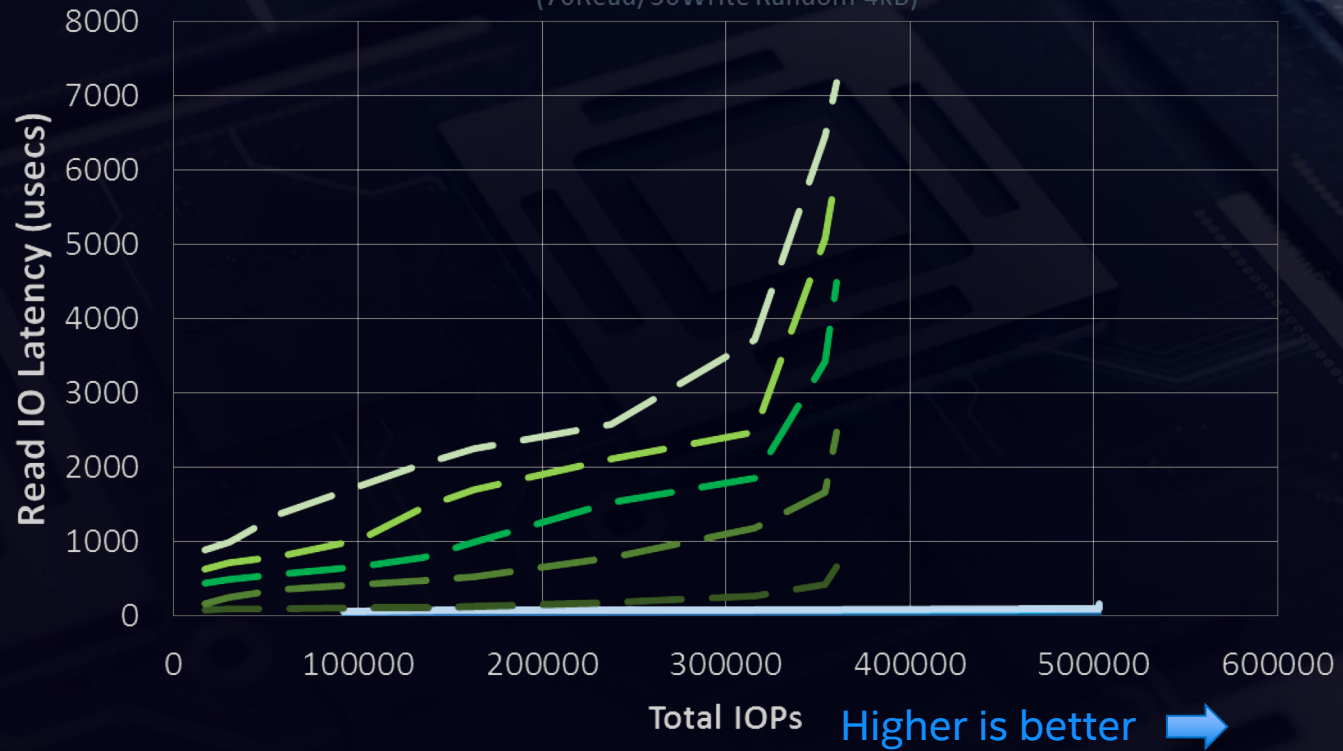
PLATFORM LEVEL INNOVATION ENABLES SYSTEM FIT

INTEL® OPTANE™ SSD

Latency vs. Load: NAND SSD vs. Intel® Optane™ DC SSD
 (Intel® DC P4610 3.2TB vs. Intel® Optane™ SSD DC P4800X 375GB)
 (70Read/30Write Random 4kB)



Lower is better



Higher is better

SYSTEM FIT

— P4800X Ave	— P4800X 99	— P4800X 99.9	— P4800X 99.99	— P4800X 99.999
— P4610 Avg	— P4610 99	— P4610 99.9	— P4610 99.99	— P4610 99.999

Software and workloads used in performance tests may have been optimized for performance only on Intel microprocessors. Performance tests, such as SYSmark and MobileMark, are measured using specific computer systems, components, software, operations and functions. Any change to any of those factors may cause the results to vary. You should consult other information and performance tests to assist you in fully evaluating your contemplated purchases, including the performance of that product when combined with other products. For more complete information visit www.intel.com/benchmarks.
 Source – Intel-tested: Measured using FIO 3.1. Common Configuration - Intel 2U Server System, OS CentOS 7.5, kernel 4.17.6-1.el7.x86_64, CPU 2 x Intel® Xeon® 6154 Gold @ 3.0GHz (18 cores), RAM 256GB DDR4 @ 2666MHz. Configuration – Intel® Optane™ SSD DC P4800X 375GB and *Intel® SSD DC P4600 1.6TB. Intel Microcode: 0x2000043; System BIOS: 00.01.0013; ME Firmware: 04.00.04.294; BMC Firmware: 1.43.9176955; FRUSDR: 1.43. The benchmark results may need to be revised as additional testing is conducted. Performance results are based on testing as of November 15, 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure.

SYSTEM LEVEL PERFORMANCE

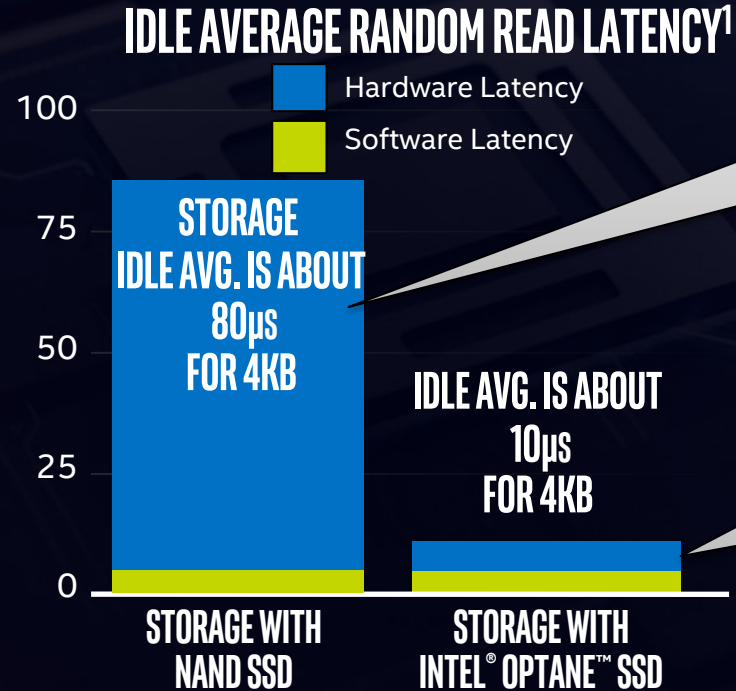
Latency vs. Load: NAND SSD vs. Intel® Optane™ DC SSD 1
 (Intel® DC P4610 3.2TB vs. Intel® Optane™ SSD DC P4800x 375GB)
 (70Read/30Write Random 4kB)



¹ Software and workloads used in performance tests may have been optimized for performance only on Intel microprocessors. Performance tests, such as SYSmark and MobileMark, are measured using specific computer systems, components, software, operations and functions. Any change to any of those factors may cause the results to vary. You should consult other information and performance tests to assist you in fully evaluating your contemplated purchases, including the performance of that product when combined with other products. For more complete information visit www.intel.com/benchmarks.
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²Source – Intel-tested: 4K 70/30 RW Performance at Low Queue Depth. Test and System Configuration: CPU: Xeon Skylake Gold 6140 FC-LGA14B 2.3GHz 24.75MB 140W 18 cores CD8067303405200, CPU Sockets: 2, RAM Capacity: 32G, RAM Model: DDR4, RAM Stuffing: NA, DIMM Slots Populated: 2 slots, PCIe Attach: CPU (not PCH lane attach), Chipset: Intel C620 chipset BIOS: SE5C620.86B.00.01.0013.030920180427, Switch/ReTimer Model/Vendor: Cable - Oculink 800mm straight SFF-8611 to right angle SFF-8611 Intel AXXCBL800CVCR, OS: CentOS 7.5, Kernel: 4.14.50(LTS), FIO version: 3.5; NVMe Driver: Inbox, C-states: Disabled, Hyper Threading: Disabled, CPU Governor (through OS): Performance Mode, EIST (Speed Step), Intel Turbo Mode=Disabled, and P-states = Enabled. The benchmark results may need to be revised as additional testing is conducted. Performance results are based on testing as of July 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure.
³Source – Intel-tested: 4K Read Latency under 500MB/s Write Workload. Measured using FIO 2.15. Tests document performance of components on a particular test, in specific systems. Differences in hardware, software, or configuration will affect actual performance. Consult other sources of information to evaluate performance as you consider your purchase. For more complete information about performance and benchmark results, visit www.intel.com/benchmarks. Common Configuration - Intel 2U Server System, OS CentOS 7.5, kernel 4.17.6-1.el7.x86_64, CPU 2 x Intel® Xeon® 6154 Gold @ 3.0GHz (18 cores), RAM 256GB DDR @ 2666MHz. Configuration – Intel® Optane™ SSD DC P4800X 375GB and Intel® SSD DC P4600 1.6TB. Latency – Average read latency measured at QD1 during 4K Random Write operations using fio-2.15. System BIOS: 00.01.0013; ME Firmware: 04.00.04.294; BMC Firmware: 1.43.9176955; FRUSDR: 1.43. The benchmark results may need to be revised as additional testing is conducted. Performance results are based on testing as of July 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure.
 For more complete information about performance and benchmark results, visit www.intel.com/benchmarks.

LATENCY IMPROVEMENT REQUIRES SYSTEM INNOVATION

Latency vs. Load: NAND SSD vs. Intel® Optane™ SSD ²
 (Intel® DC P4610 3.2TB vs. Intel® Optane™ SSD DC P4800x 375GB)



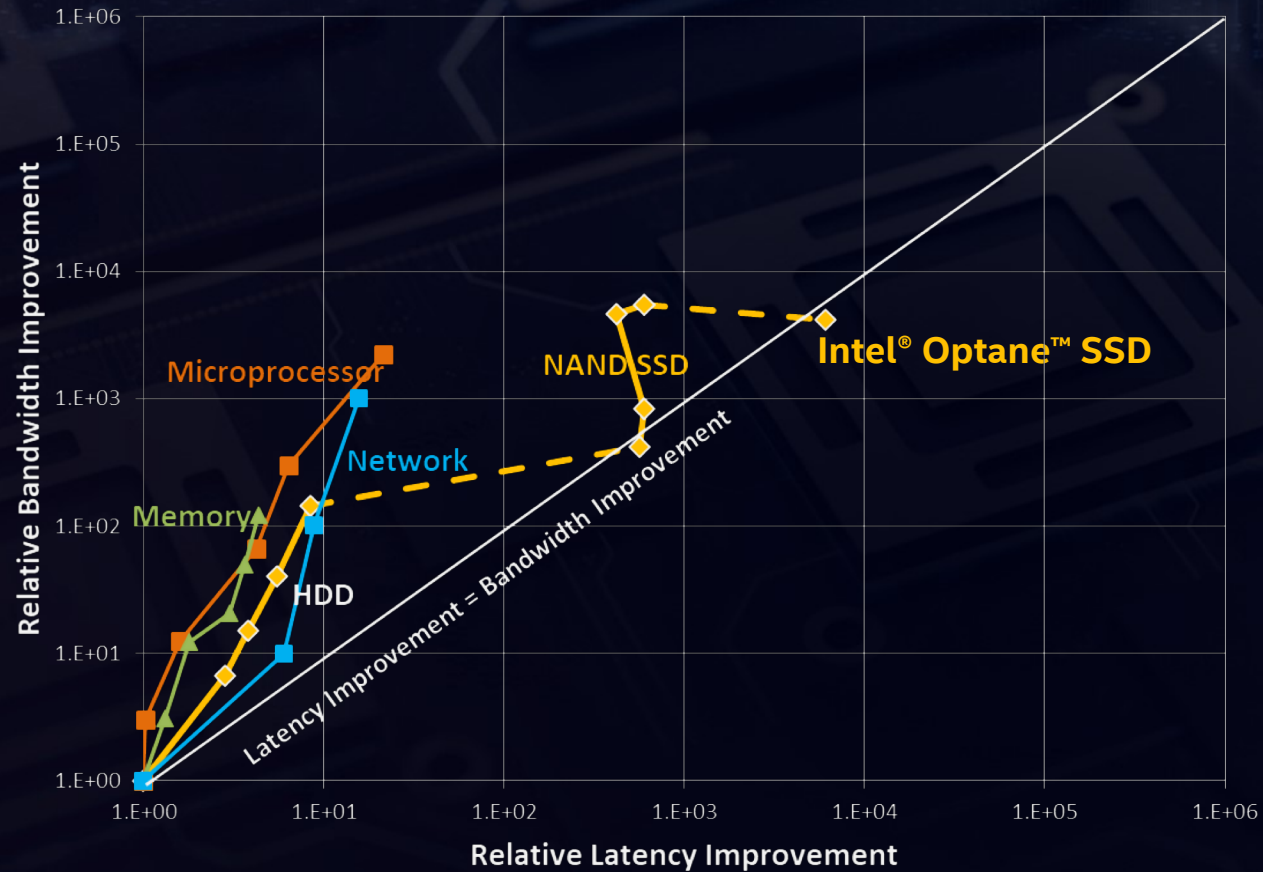
NAND SSD latency dominated by media latency

Optane SSD latency balanced between SSD and System

¹ Source – Intel-tested: Average read latency measured at queue depth 1 during 4k random write workload. Measured using FIO 3.1. Common Configuration - Intel 2U Server System, OS CentOS 7.5, kernel 4.17.6-1.el7.x86_64, CPU 2 x Intel® Xeon® 6154 Gold @ 3.0GHz (18 cores), RAM 256GB DDR4 @ 2666MHz. Configuration – Intel® Optane™ SSD DC P4800X 375GB and Intel® SSD DC P4600 1.6TB. Latency – Average read latency measured at QD1 during 4K Random Write operations using FIO 3.1. Intel Microcode: 0x2000043; System BIOS: 00.01.0013; ME Firmware: 04.00.04.294; BMC Firmware: 1.43.91f76955; FRUSDR: 1.43. SSDs tested were commercially available at time of test. The benchmark results may need to be revised as additional testing is conducted. Performance results are based on testing as of July 24, 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure. Software and workloads used in performance tests may have been optimized for performance only on Intel microprocessors. Performance tests, such as SYSmark and MobileMark, are measured using specific computer systems, components, software, operations and functions. Any change to any of those factors may cause the results to vary. You should consult other information and performance tests to assist you in fully evaluating your contemplated purchases, including the performance of that product when combined with other products. For more complete information visit www.intel.com/benchmarks.

² See Note on previous slide

PERFORMANCE: TECHNOLOGY SCALING



Source: "Latency lags Bandwidth"
– David Patterson Comms. of the
ACM, Oct 2004 Vol 47, No 10

NAND and Optane SSD data
points added by Intel Based on
product brief specifications for
Intel NAND and Optane SSDs
available at www.intel.com

INTEL® OPTANE™ SSDS PUT STORAGE BACK IN THROUGHPUT/LATENCY BALANCE

MEMORY AND STORAGE HIERARCHY

MEMORY

10s GB
<100ns

DRAM
HOT TIER

CAPACITY GAP

STORAGE

IMPROVING
SSD PERFORMANCE

intel OPTANE DC
SOLID STATE DRIVE

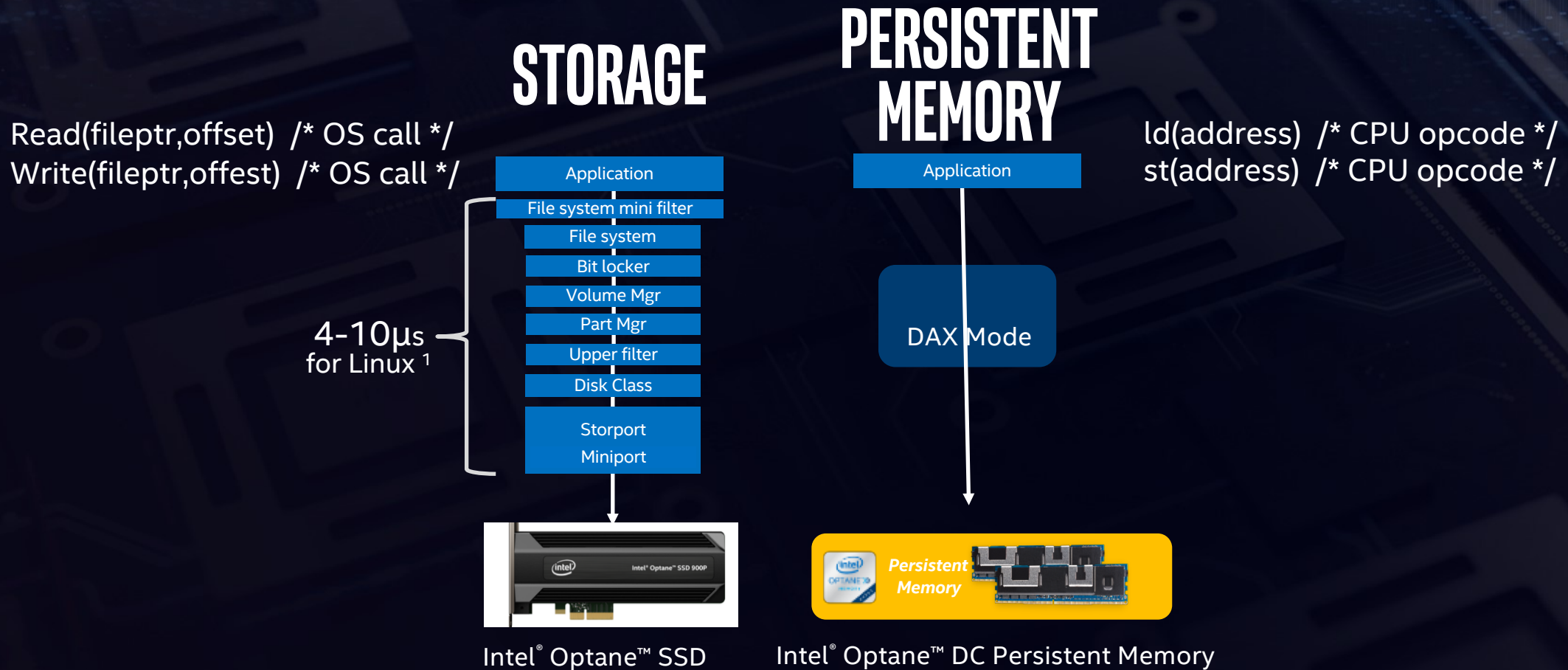
1 Intel® Optane™ SSD:
1sTB
<10μsecs

3D NAND SSD
WARM TIER

STORAGE PERFORMANCE GAP

HDD / TAPE
COLD TIER

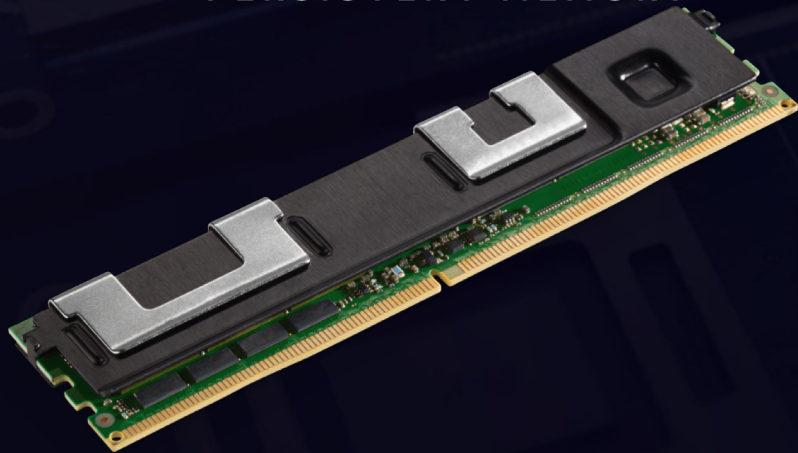
LOW LATENCY SOFTWARE PATH



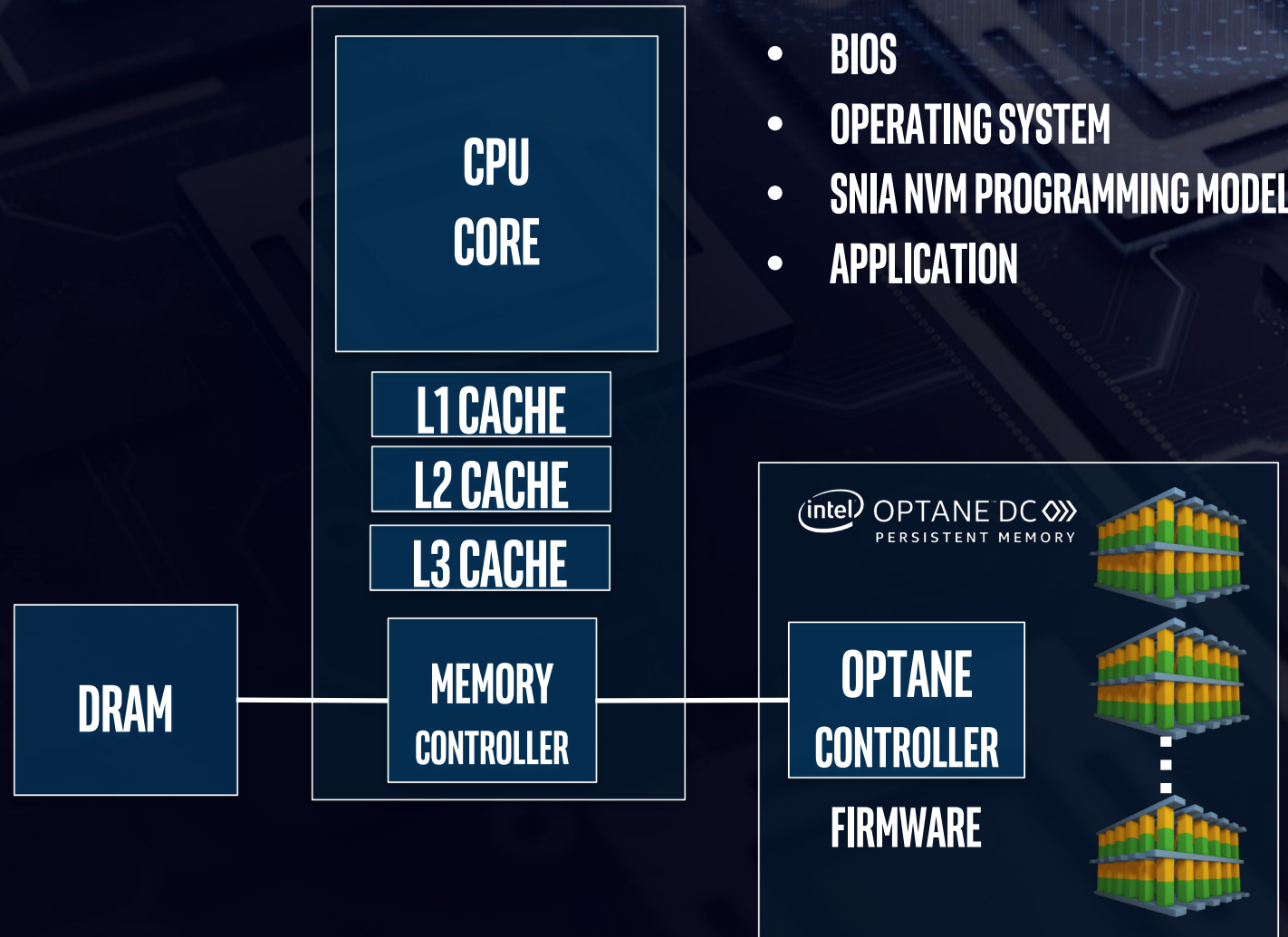
1. Platform Storage Performance With 3D Xpoint Technology. Frank Hady, Annie Foong, Bryan Veal, Dan Williams, Proceedings of the IEEE. Vol 105, No. 9, Sept 2017 <http://ieeexplore.ieee.org/stamp/stamp.jsp?arnumber=8003284>
Towards SSD-Read Enterprise Platforms. Annie Foong, Bryan Veal, Frank Hady. ASMS 2010 – First International Workshop on Accelerating Data Management Systems Using Modern Processor and Storage Architecture. http://www.vldb2010.org/proceedings/files/vldb_2010_workshop/ADMS_2010/adms10-foong.pdf September 2010

PERSISTENT MEMORY PLATFORM SUPPORT

 **OPTANE™ DC** 
PERSISTENT MEMORY

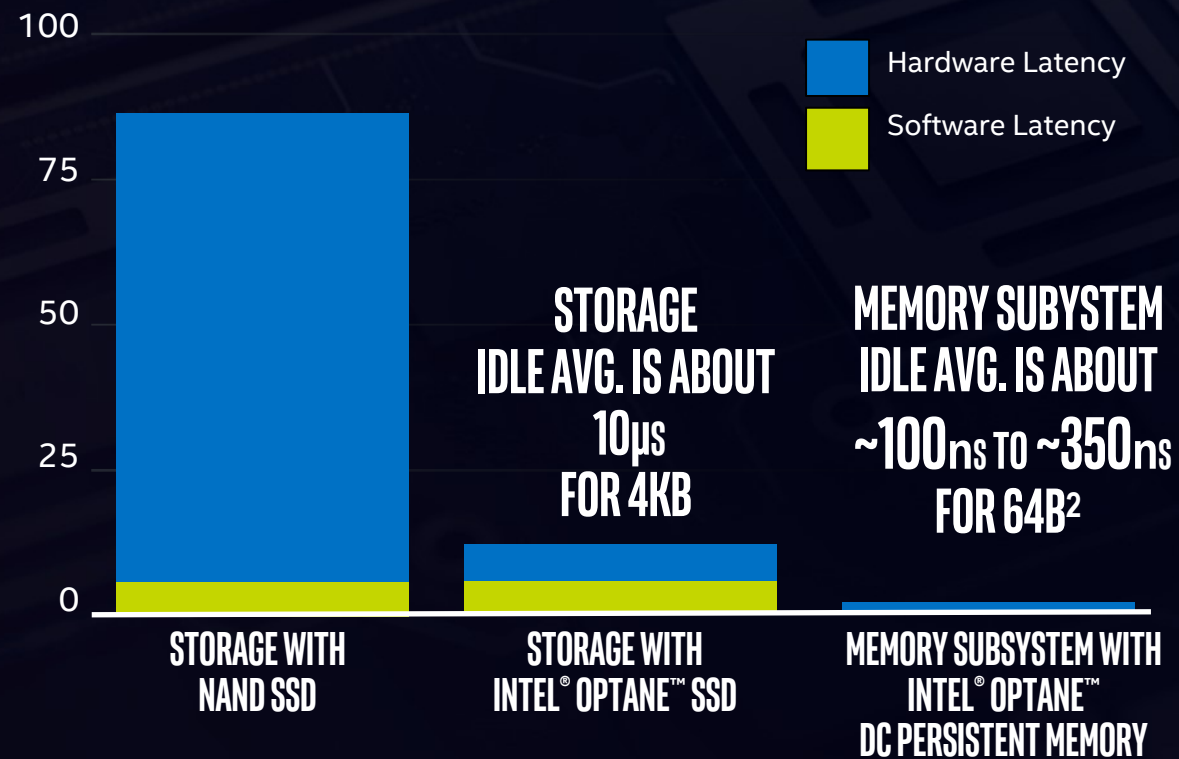


Direct Load/Store Access
Native Persistence
128, 256, 512GB
DDR4 Pin Compatible



LOW LATENCY SYSTEM ACCESS TO PERSISTENT MEMORY

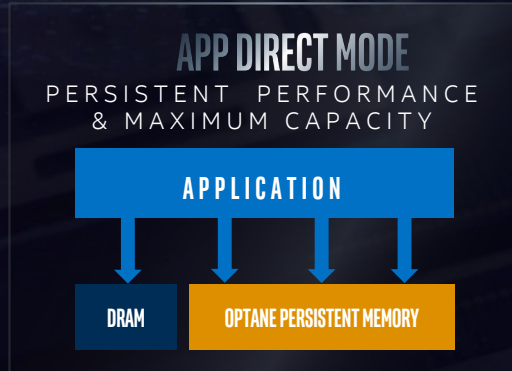
IDLE AVERAGE RANDOM READ LATENCY¹



¹Source: Intel-tested: Average read latency measured at queue depth 1 during 4k random write workload. Measured using FIO 3.1. comparing Intel Reference platform with Optane™ SSD DC P4800X 375GB and Intel® SSD DC P4600 1.6TB compared to SSDs commercially available as of July 1, 2018. Performance results are based on testing as of July 24, 2018 and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure. For more complete information about performance and benchmark results, visit www.intel.com/benchmarks.

² App Direct Mode, NeonCity, LBG B1 chipset, CLX B0 28 Core (QDF QQYZ), Memory Conf 192GB DDR4 (per socket) DDR 2666 MT/s, Optane DCPMM 128GB, BIOS 561.D09, BKC version WW48.5 BKC, Linux OS 4.18.8-100.fc27, Spectre/Meltdown Patched (1,2,3, 3a)

INTEL® OPTANE™ PERSISTENT MEMORY: APP DIRECT

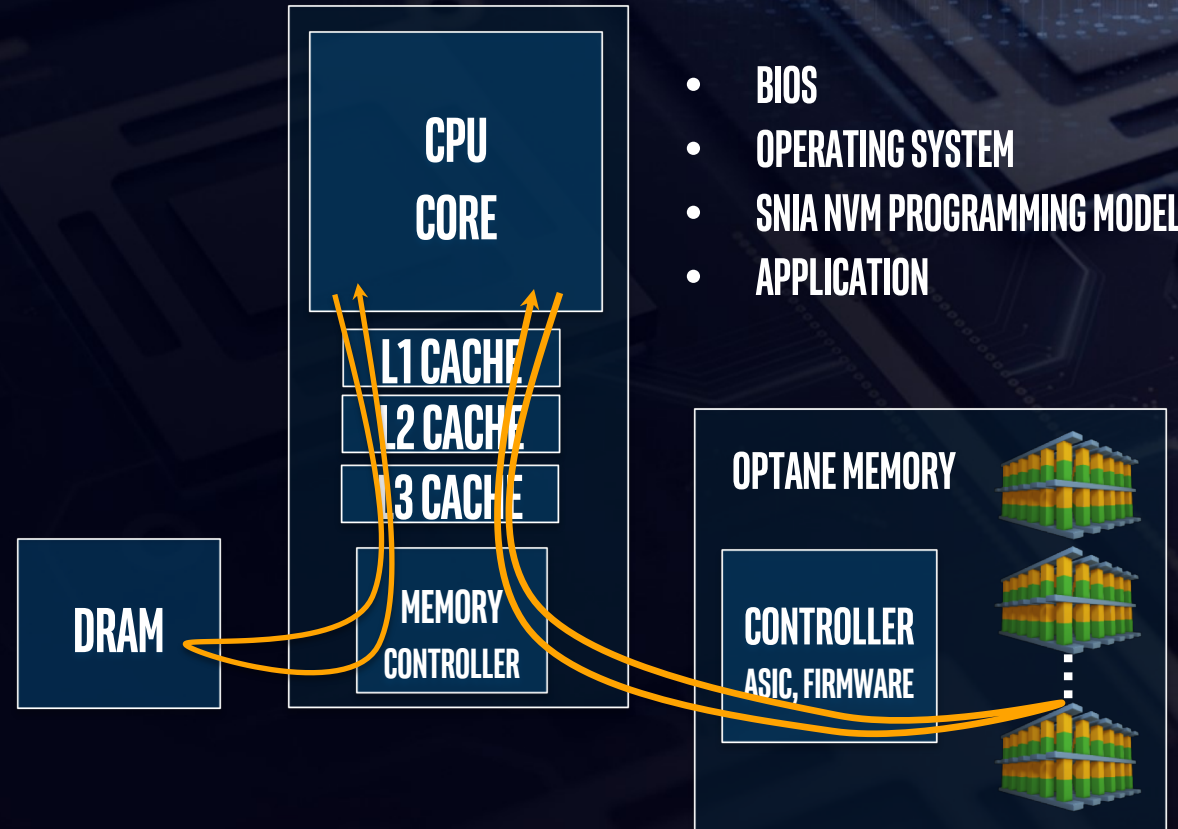


App Direct Mode provides the persistent memory programming model

- Reported to OS by ACPI
- Linux and Windows expose via "DAX" file systems

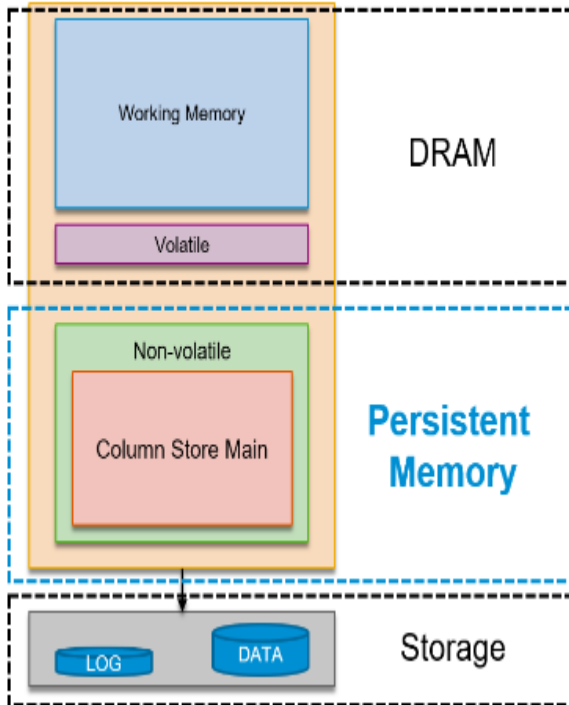
Several use cases supported by OS & PMDK APIs

- Persistent memory, non-paged (no DRAM footprint when accessed)
- Volatile App Direct, an explicit pool of volatile memory
- Storage over App Direct, a very fast SSD built on persistent memory



APP DIRECT USAGE EXAMPLE

SAP HANA controls what is placed in Persistent Memory and what remains in DRAM.



Volatile data structures remain in DRAM.

Column Store Main moves to Persistent Memory

- More than 95% of data in most HANA systems.
- Loading of tables into memory at startup becomes obsolete.
- Lower TCO, larger capacity.

No changes to the persistence.

Developer placed data structures

“SAP HANA knows which data structures benefit most from persistent memory. SAP HANA automatically detects persistent memory hardware and adjusts itself by automatically placing these data structures on persistent memory, while all others remain in DRAM”

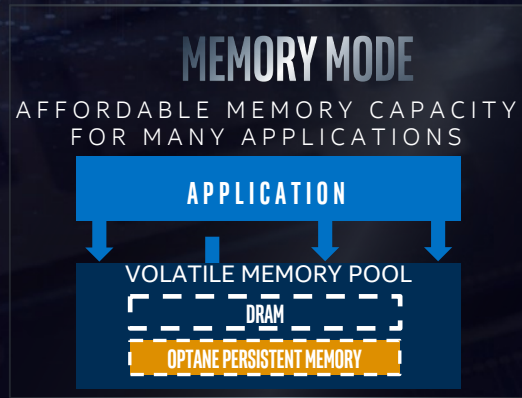
- Column Store Main in Persistent Memory
 - 90% of the data footprint
 - Nonvolatile – no initial load time
- High perf, volatile in DRAM
- SSDs still used for row store, column delta, replication, backups...

Source: “SAP HANA & Persistent Memory”
– Andreas Schuster

Dec 3 2018, <https://blogs.sap.com/2018/12/03/sap-hana-persistent-memory/>

INTEL® OPTANE™ PERSISTENT MEMORY :

MEMORY MODE

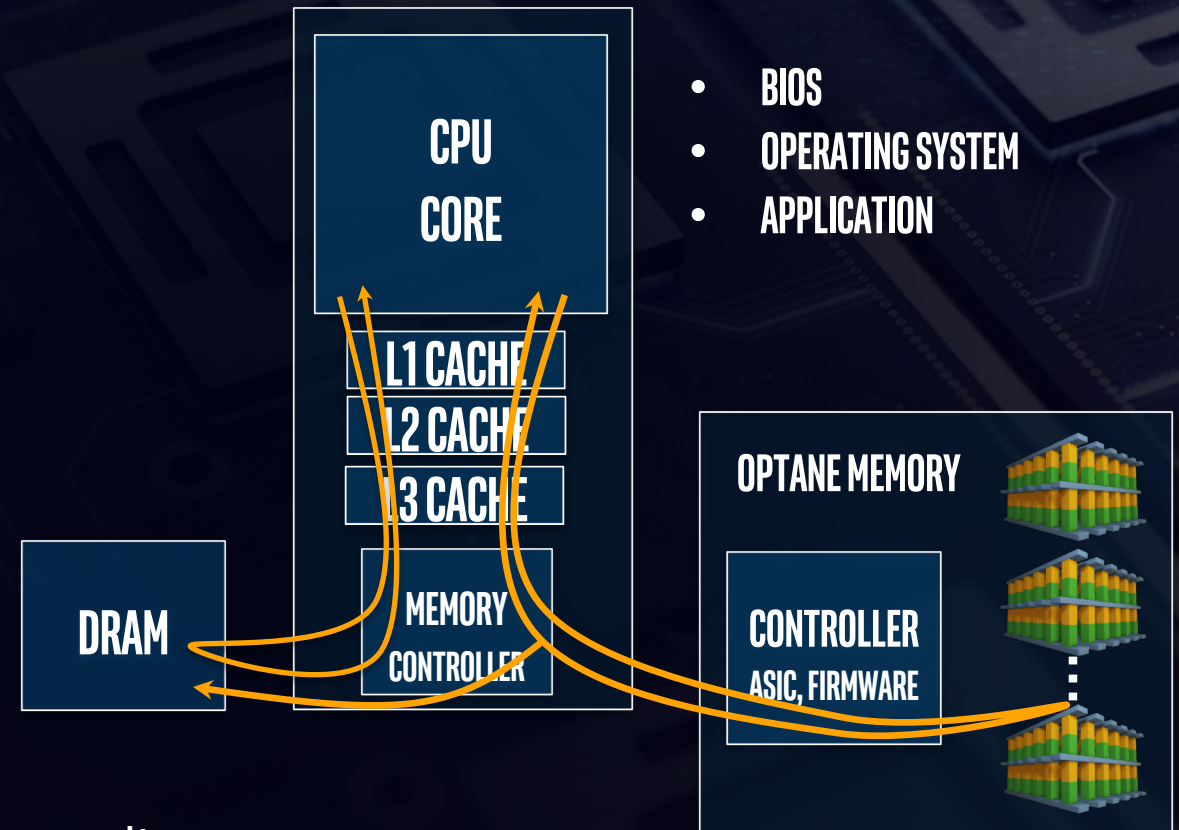


Memory Mode provides familiar volatile memory programming model

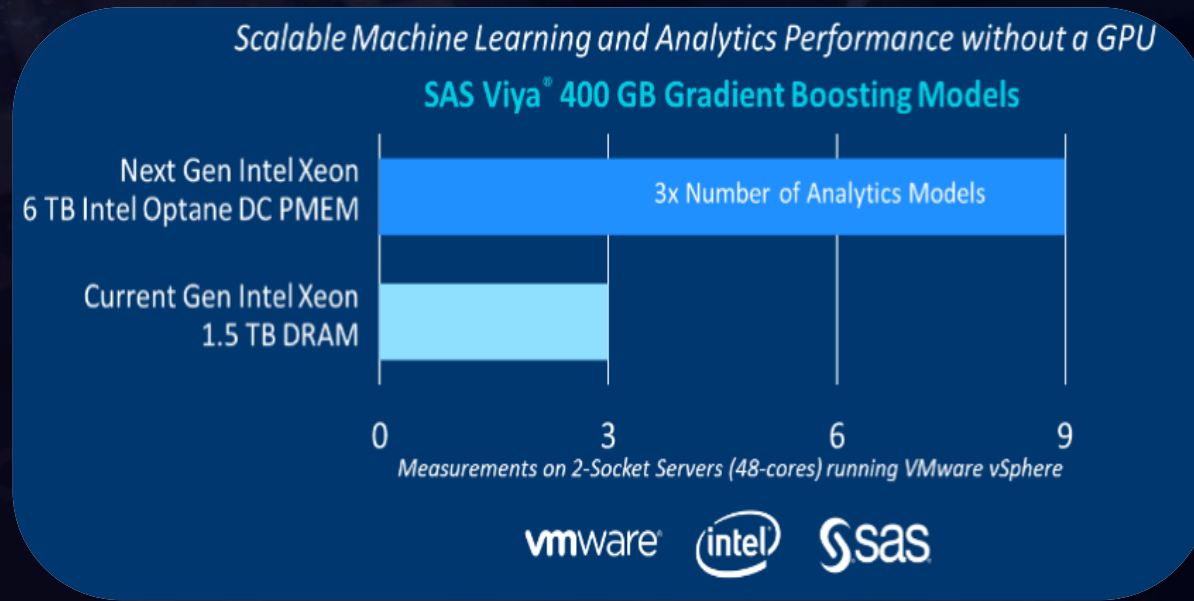
- Additional layer of caching: DRAM as WB cache
- Hardware managed, software sees very high capacity memory (6 TB)

Range of use cases supported

- No software change – big memory
- Applications/Algorithms changes for new hierarchy/capacity



MEMORY MODE USAGE EXAMPLE



VMware vSphere* using memory mode:

“When used in memory mode, the new Intel memory technology can greatly increase the memory capacity available to software in a platform when compared with the capacity of DRAM. This increase in capacity requires no changes to your existing software, operating systems, or virtual machines.”

- Developer allocates VM memory images in “memory”
- Platform memory controller caches active VM data in DRAM for use

Source: “Extending Memory Capacity with VMware vSphere and Upcoming Intel Optane Memory Technology”
– Rich Brunner

Nov 6 2018, <https://octo.vmware.com/vmware-and-intel-optane-dc-pmem/>

Performance results have been estimated based on SAS internal tests as of 11/05/2018 using future version of VMware vSphere, SAS Viya 400GB Gradient Boosting Models running Linux with Intel® Optane™ DC persistent memory vs. DRAM-based server and may not reflect all publicly available security updates. As measured by VMWARE on system listed as 2-CPU socket server, Intel® Cascade lake, future version of VMware vSphere, 6TB Intel® Optane™ DC Persistent Memory in Memory Mode, versus 2-CPU socket server, Intel® Cascade lake, future version of VMware vSphere, 1.5TB DDR4 DRAM 3x 3.6 TB SSD. Performance results are based on testing as of [INSERT DATE] and may not reflect all publicly available security updates. See configuration disclosure for details. No product can be absolutely secure. For more complete information about performance and benchmark results, visit www.intel.com/benchmarks..

COMPLETE IN PERFORMANCE, CAPACITY, FIT

MEMORY

10s GB
<100ns

DRAM
HOT TIER

PERSISTENT MEMORY

GROWING
MEMORY CAPACITY

intel OPTANE DC
PERSISTENT MEMORY

100s GB
<1usec

STORAGE

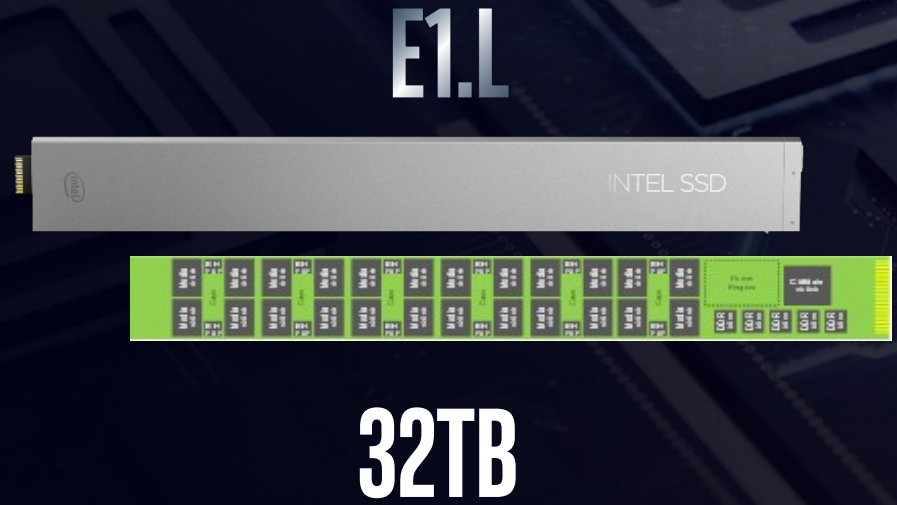
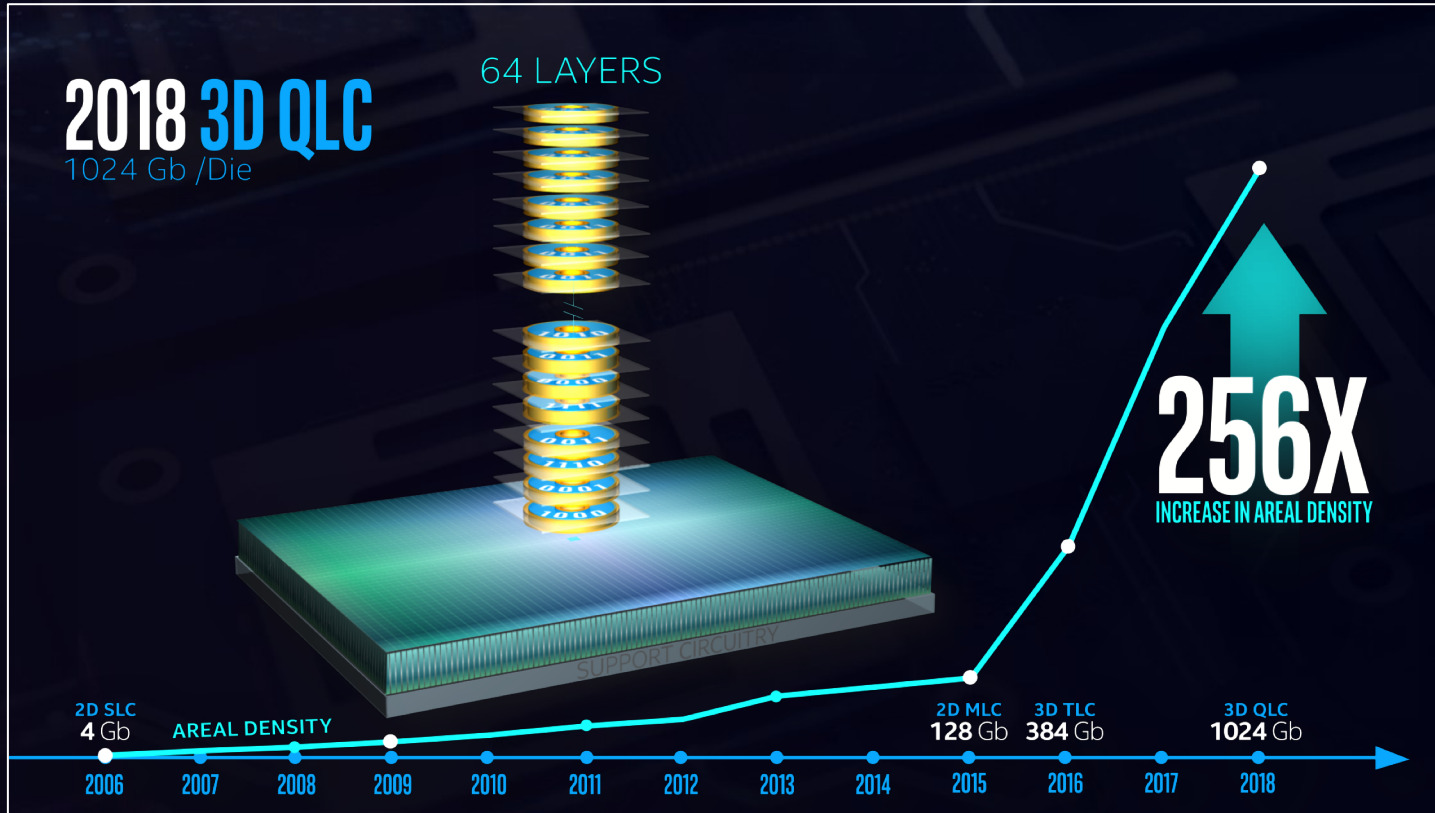
intel OPTANE DC
SOLID STATE DRIVE

3D NAND SSD
WARM TIER

STORAGE PERFORMANCE GAP

HDD / TAPE
COLD TIER

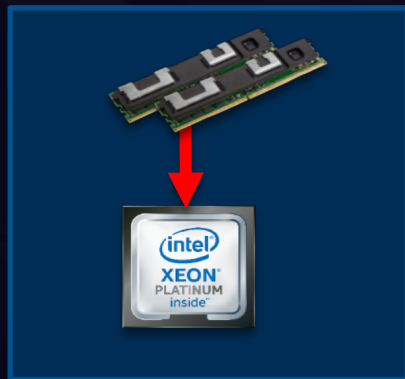
NAND TECHNOLOGY ADVANCEMENT



THE FUTURE OF DATA CENTER STORAGE & MEMORY

DATA/METADATA CACHE IN PM

w/INTEL® OPTANE™ DC
PERSISTENT MEMORY



DATA STORAGE IN 1PB IN 1U

w/INTEL® 3D NAND SSDs



COMPLETE IN PERFORMANCE, CAPACITY, FIT

MEMORY

**DRAM
HOT TIER**

10s GB
<100ns

PERSISTENT MEMORY

**GROWING
MEMORY CAPACITY**

intel OPTANE DC
PERSISTENT MEMORY

100s GB
<1usec

STORAGE

**IMPROVING
SSD PERFORMANCE**

intel OPTANE DC
SOLID STATE DRIVE

1s TB
<10µsecs

INTEL® QLC 3D NAND SSD

10s TB
<100µsecs

**DELIVERING
EFFICIENT STORAGE**

**HDD / TAPE
COLD TIER**

10s TB
<10 msecs



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